

RF AMPLIFIER

Medium Power Amplifier

MODEL *BXMP1005*

Available as: WNMP1005, 10 Pin .625" Sq. Surface Mount (SG4)
 BXMP1005, SMA Connectorized Housing

Features

- High Power Output: 1 Watt
- Two Stage Gain: 21 dB
- SMA Connectorized Housing

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point +66 dBm (Typ.)
 Second Order Two Tone Intercept Point +63 dBm (Typ.)
 Third Order Two Tone Intercept Point..... +43 dBm (Typ.)

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	10 - 200 MHz	10 - 200 MHz
Gain (dB)	21	20 Min.
Power @ 1 dB Comp. (dBm)	30	28.5 Min.
Reverse Isolation (dB)	-15	-13 Max.
VSWR In	1.5:1	2:0:1 Max.
Out	1.7:1	2:0:1 Max.
Noise figure (dB)	5.5	6.5 Max.
Power Vdc	+15	+15
m A	300	320 Max.

Maximum Ratings

Ambient Operating Temperature -30°C to + 85 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 150 °C
 DC Voltage + 18 Volts
 Continuous RF Input Power + 20 dBm
 Short Term RF Input Power ... 200 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.2 Watt (3 µsec Max.)

Legend ——— + 25 °C - - - - + 60°C ······ 0 °C

Note: Care should always be taken to effectively ground the case of each unit.

Typical Performance Data

